



DIP Type (VC)TCXO (Full Size)



■ FEATURES:

- For automatic assembly
- Compactness and light weight
- VCTCXO available

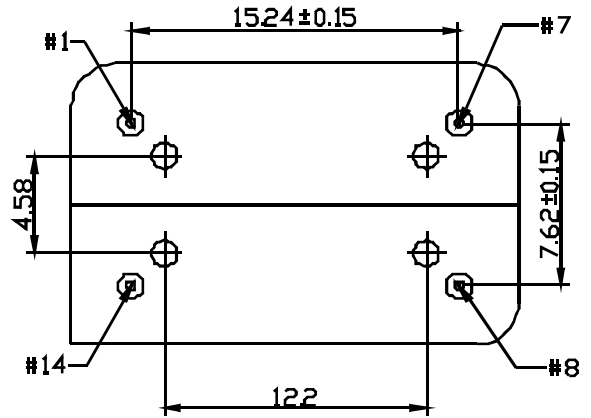
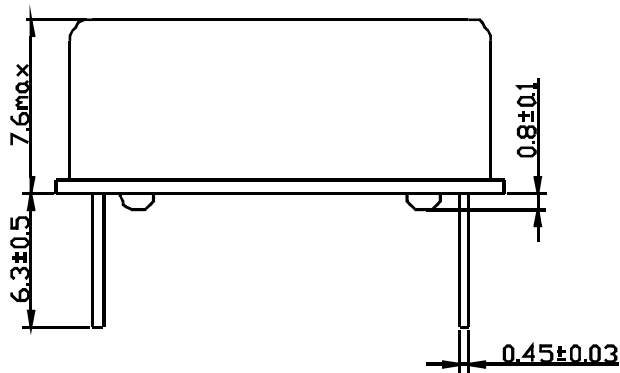
■ SPECIFICATION:

Parameter	Min	Typical	Max	Unit
Package	FULL SIZE			
Frequency Range(F0)	1.25		40.00	MHz
Standard Frequency	13.000、16.368、19.200、26.000			MHz
Frequency Stability @T <sup>OPR</sup> ( $\Delta F/F_0$ )			$\pm 1.0(0^\circ\text{C to }+50^\circ\text{C})$ $\pm 1.5(0^\circ\text{C to }+70^\circ\text{C})$ $\pm 2.0(-20^\circ\text{C to }+70^\circ\text{C})$ $\pm 2.5(-30^\circ\text{C to }+75^\circ\text{C})$ $\pm 3.0(-40^\circ\text{C to }+85^\circ\text{C})$	PPM
Frequency Stability @ Load( $\Delta F/F_0$ )			$\pm 0.3(\pm 10\% \text{ Load Change})$	PPM
Frequency Stability @ Vcc( $\Delta F/F_0$ )			$\pm 0.2$	PPM
Aging Per Year			$\pm 1.0$	PPM
Phase Noise@19.20MHz			-110 dBC/Hz(100Hz) -140 dBC/Hz(1KHz) -150 dBC/Hz(10KHz)	
Operating Temperature Range(T <sup>OPR</sup> )	-40		+85	°C
Storage Temperature Range(T <sup>STG</sup> )	-55		+125	°C
Operating Voltage(Vcc)	5.0 $\pm$ 10% or 3.3 $\pm$ 10%			V
Input Current On Load(Icc)	Clipped Sine Wave		2(1.25.00 to 15.99MHz)	mA
	Clipped Sine Wave		3(16.00 to 24.00MHz)	
	CMOS		25(2.50 to 40.00MHz)	
Start Time			2	ms
Output Load	10K $\Omega$ /10 PF(Clipped Sine Wave) 、 15PF(CMOS)			
Output Level(Clipped Sine Wave)	0.8Vp-p			V
Output High Voltage Level("1")(CMOS)	90%VCC			V
Output Low Voltage Level("0")(CMOS)			10%VCC	V
Control Voltage Range(Vcontrol)	20%VCC		80%VCC	V
Pull ability@Control Voltage Range	$\pm 5.0$			PPM





■ DIMENSIONS AND PIN FUNCTION:



PIN	Function
#1	NC/Vcontrol
#7	GND
#8	Output
#14	Vcc

Full Size Unit:mm

